

1N5221B THRU 1N5267B

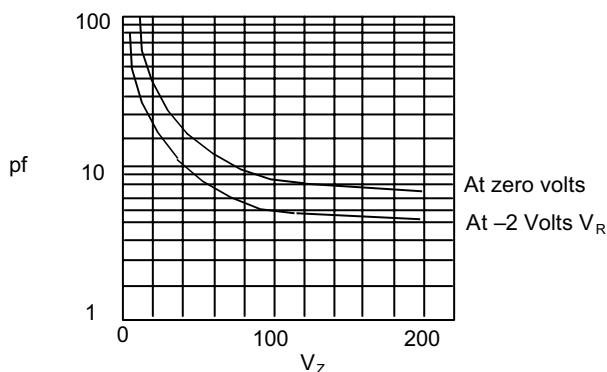
Features

- Wide Voltage Range Available
- Glass Package
- High Temp Soldering: 260°C for 10 Seconds At Terminals
- Marking : Cathode band and type number
- Lead Free Finish/Rohs Compliant (Note1) ("P" Suffix designates Compliant. See ordering information)
- Moisture Sensitivity: Level 1

Maximum Ratings

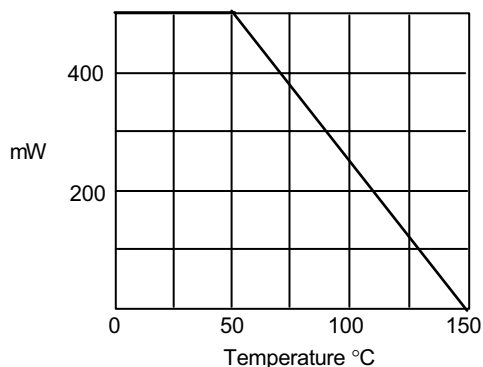
- Operating Temperature: -55°C to +150°C
- Storage Temperature: -55°C to +150°C
- 500 mWatt DC Power Dissipation
- Power Derating: 4.0mW/°C above 50°C
- Forward Voltage @ 200mA: 1.1 Volts

Figure 1 - Typical Capacitance



Typical Capacitance (pf) – versus – Zener voltage (V_Z)

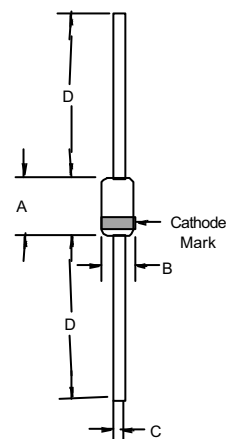
Figure 2 - Derating Curve



Power Dissipation (mW) - Versus - Temperature °C

**500 mW
Zener Diode
2.4 to 75 Volts**

DO-35



DIMENSIONS					
DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	---	.166	---	4.2	
B	---	.079	---	2.00	
C	---	.020	---	.52	
D	1.000	---	25.40	---	

Note: 1. Lead in Glass Exemption Applied, see EU Directive Annex 7(C)-I.

1N5221B thru 1N5267B

ELECTRICAL CHARACTERISTICS @25°C

MCC PART NUMBER	NOMINAL ZENER VOLTAGE V_Z @ I_{ZT} VOLTS	TEST CURRENT I_{ZT} mA	MAXIMUM ZENER IMPEDANCE 'B' SUFFIX ONLY		MAXIMUM REVERSE LEAKAGE CURRENT		MAX. ZENER VOLTAGE TEMP COEFFICIENT 'B' SUFFIX ONLY % / °C
			Z_{ZT} @ I_{ZT}	Z_{ZK} @ $I_{ZK} = 0.25\text{mA}$	I_R @ V_R		
			OHMS	OHMS	μA	VOLTS	
1N5221B	2.4	20	30	1200	100	1.0	-0.085
1N5222B	2.5	20	30	1250	100	1.0	-0.085
1N5223B	2.7	20	30	1300	75	1.0	-0.080
1N5224B	2.8	20	30	1400	75	1.0	-0.080
1N5225B	3.0	20	29	1600	50	1.0	-0.075
1N5226B	3.3	20	28	1600	25	1.0	-0.070
1N5227B	3.6	20	24	1700	15	1.0	-0.065
1N5228B	3.9	20	23	1900	10	1.0	-0.060
1N5229B	4.3	20	22	2000	5.0	1.0	±0.055
1N5230B	4.7	20	19	1900	5.0	2.0	±0.030
1N5231B	5.1	20	17	1600	5.0	2.0	±0.030
1N5232B	5.6	20	11	1600	5.0	3.0	+0.038
1N5233B	6.0	20	7.0	1600	5.0	3.5	+0.038
1N5234B	6.2	20	7.0	1000	5.0	4.0	+0.045
1N5235B	6.8	20	5.0	750	3.0	5.0	+0.050
1N5236B	7.5	20	6.0	500	3.0	6.0	+0.058
1N5237B	8.2	20	8.0	500	3.0	6.5	+0.062
1N5238B	8.7	20	8.0	600	3.0	6.5	+0.065
1N5239B	9.1	20	10	600	3.0	7.0	+0.068
1N5240B	10	20	17	600	3.0	8.0	+0.075
1N5241B	11	20	22	600	2.0	8.4	+0.076
1N5242B	12	20	30	600	1.0	9.1	+0.077
1N5243B	13	9.5	13	600	0.5	9.9	+0.079
1N5244B	14	9.0	15	600	0.1	10	+0.082
1N5245B	15	8.5	16	600	0.1	11	+0.082
1N5246B	16	7.8	17	600	0.1	12	+0.083
1N5247B	17	7.4	19	600	0.1	13	+0.084
1N5248B	18	7.0	21	600	0.1	14	+0.085
1N5249B	19	6.6	23	600	0.1	14	+0.086
1N5250B	20	6.2	25	600	0.1	15	+0.086
1N5251B	22	5.6	29	600	0.1	17	+0.087
1N5252B	24	5.2	33	600	0.1	18	+0.088
1N5253B	25	5.0	35	600	0.1	19	+0.089
1N5254B	27	4.6	41	600	0.1	21	+0.090
1N5255B	28	4.5	44	600	0.1	21	+0.091
1N5256B	30	4.2	49	600	0.1	23	+0.091
1N5257B	33	3.8	58	700	0.1	25	+0.092
1N5258B	36	3.4	70	700	0.1	27	+0.093
1N5259B	39	3.2	80	800	0.1	30	+0.094
1N5260B	43	3.0	93	900	0.1	33	+0.095
1N5261B	47	2.7	105	1000	0.1	36	+0.095
1N5262B	51	2.5	125	1100	0.1	39	+0.096
1N5263B	56	2.2	150	1300	0.1	43	+0.096
1N5264B	60	2.1	170	1400	0.1	46	+0.097
1N5265B	62	2.0	185	1400	0.1	47	+0.097
1N5266B	68	1.8	230	1600	0.1	52	+0.097
1N5267B	75	1.7	270	1700	0.1	56	+0.098

NOTE 1: suffix "B" = 5% tolerance on nominal Zener voltage, suffix "C" signifies 2%.

NOTE 2: The electrical characteristics are measured after allowing the device to stabilize for 20 seconds.

NOTE 3: Temperature coefficient (α_{VZ}). Test conditions for temperature coefficient are as follows:

- $I_{ZT} = 7.5\text{mA}$, $T_1 = 25^\circ\text{C}$, $T_2 = 125^\circ\text{C}$ (1N5221 thru 1N5242)
- $I_{ZT} = \text{Rated } I_{ZT}$, $T_1 = 25^\circ\text{C}$, $T_2 = 125^\circ\text{C}$ (1N5243 thru 1N5267)

Device to be temperature stabilized with current applied prior to reading breakdown voltage at the specified ambient temperature.

1N5221B thru 1N5267B

Figure 1
Zener Voltage versus Zener Current – $V_Z = 1$ thru 16 Volts

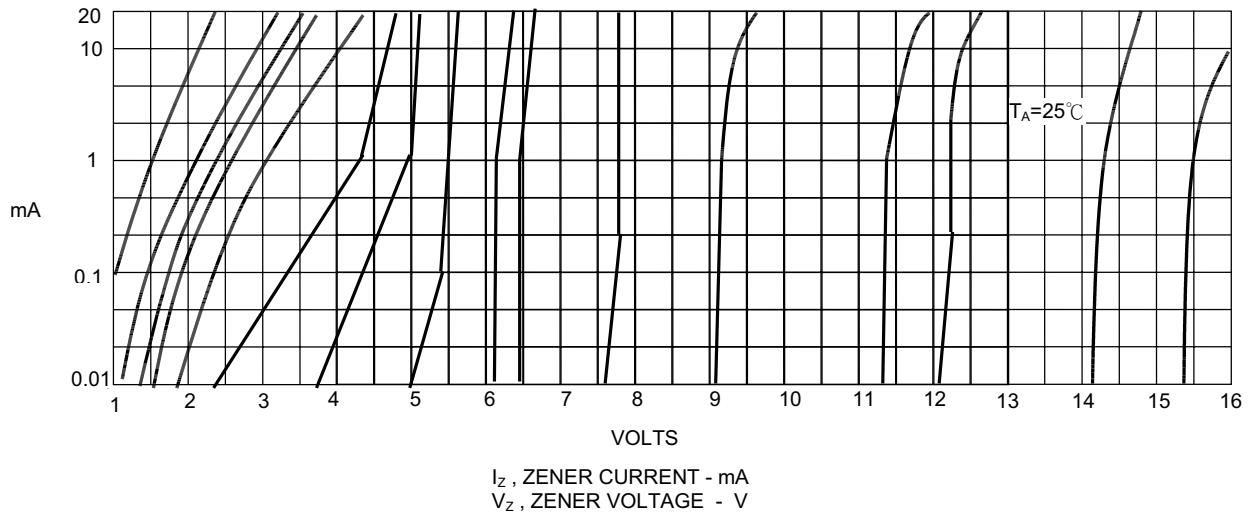
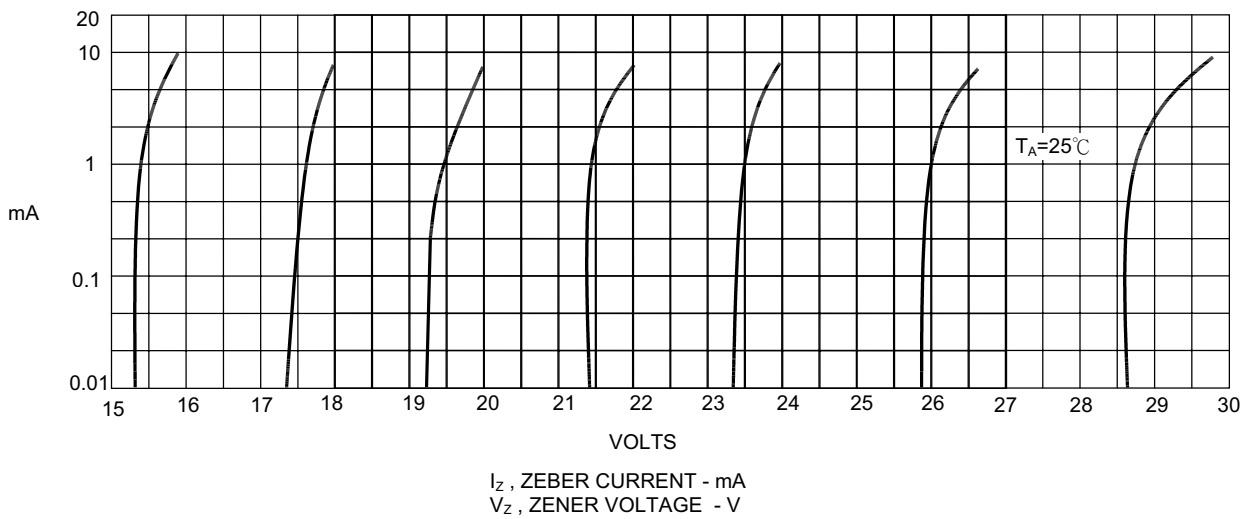


Figure 2
Zener Voltage versus Zener Current – $V_Z = 15$ thru 30 Volts



1N5221B thru 1N5267B

Figure 3
Zener Voltage versus Zener Current – $V_z = 30$ thru 75 Volts

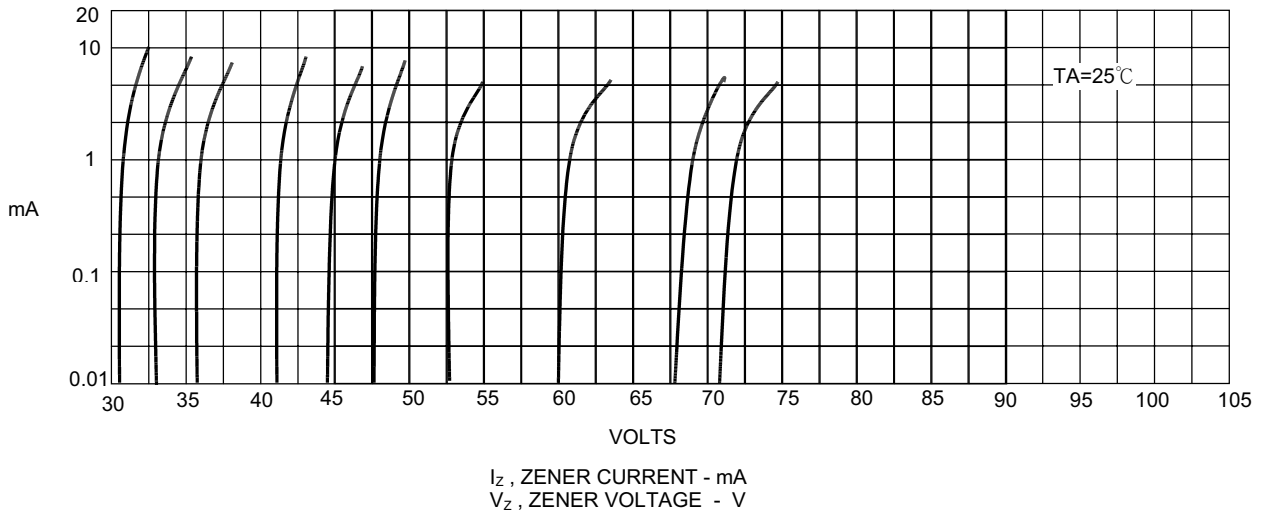
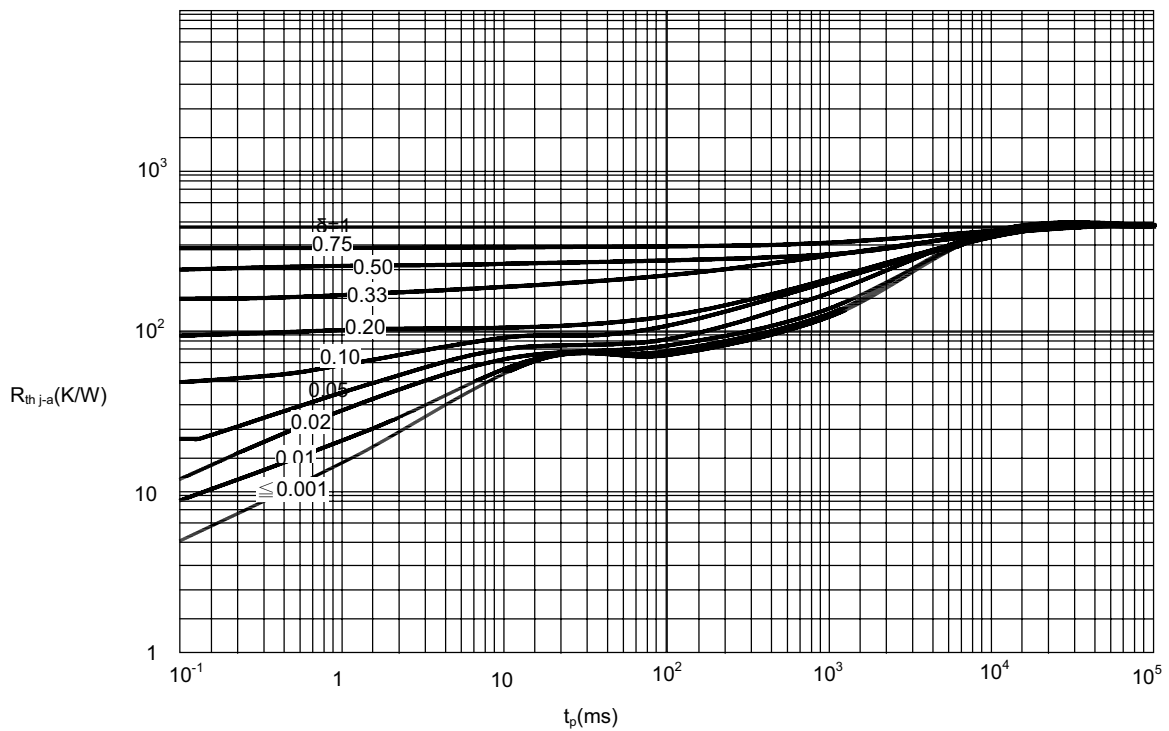


Figure 4
Thermal resistance from junction to ambient as a function of pulse duration



Ordering Information :

Device	Packing
Part Number-TP	Tape&Reel: 10Kpcs/Reel
Part Number-AP	Ammo Packing: 5Kpcs/Ammo Box
Part Number-BP	Bulk: 100Kpcs/Carton

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